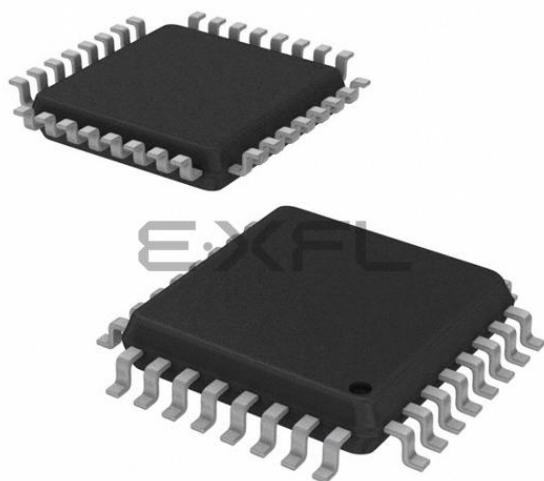




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Details

Product Status	Active
Core Processor	STM8A
Core Size	8-Bit
Speed	16MHz
Connectivity	I ² C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	28
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	640 x 8
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 7x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	32-LQFP
Supplier Device Package	32-LQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm8af6226itcy

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4.14.1 LINUART

Main features

- 1 Mbit/s full duplex SCI
- SPI emulation
- High precision baud rate generator
- Smartcard emulation
- IrDA SIR encoder decoder
- LIN mode
- Single wire half duplex mode

LIN mode

Master mode:

- LIN break and delimiter generation
- LIN break and delimiter detection with separate flag and interrupt source for read back checking.

Slave mode:

- Autonomous header handling – one single interrupt per valid header
- Mute mode to filter responses
- Identifier parity error checking
- LIN automatic resynchronization, allowing operation with internal RC oscillator (HSI) clock source
- Break detection at any time, even during a byte reception
- Header errors detection:
 - Delimiter too short
 - Synch field error
 - Deviation error (if automatic resynchronization is enabled)
 - Framing error in synch field or identifier field
 - Header time-out

5 Pinout and pin description

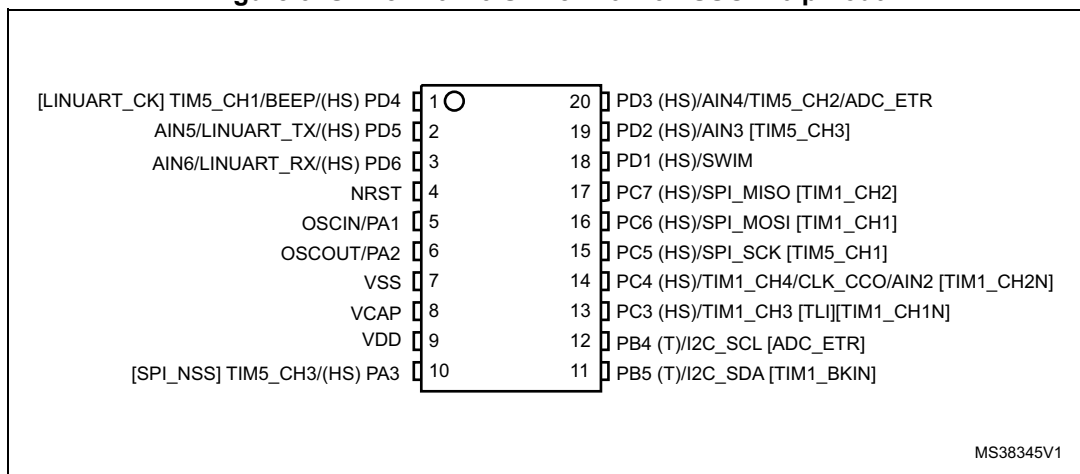
The following table presents the meaning of the abbreviations in use in the pin description tables in this section.

Table 5. Legend/abbreviations for pinout tables

Type	I= input, O = output, S = power supply	
Level	Input	CM = CMOS (standard for all I/Os)
	Output	HS = High sink
Output speed	O1 = Slow (up to 2 MHz) O2 = Fast (up to 10 MHz) O3 = Fast/slow programmability with slow as default state after reset O4 = Fast/slow programmability with fast as default state after reset	
Port and control configuration	Input	float = floating, wpu = weak pull-up
	Output	T = true open drain, OD = open drain, PP = push pull
Reset state	Bold X (pin state after internal reset release). Unless otherwise specified, the pin state is the same during the reset phase and after the internal reset release.	

5.1 TSSOP20 pinouts and pin descriptions

Figure 3. STM8AF6213/STM8AF6223 TSSOP20 pinout



1. (HS) high sink capability.
2. (T) true open drain (P-buffer and protection diode to V_{DD} not implemented).
3. [] alternate function remapping option (if the same alternate function is shown twice, it indicates an exclusive choice not a duplication of the function).

Table 6. STM8AF6213/STM8AF6223 TSSOP20 pin description (continued)

TSSOP	Pin name	Type	Input			Output				Main function (after reset)	Default alternate function	Alternate function after remap [option bit]
			floating	wpu	Ext. interrupt	High sink ⁽¹⁾	Speed	OD	PP			
19	PD2/AIN3 [TIM5_CH3]	I/O	X	X	X	HS	O3	X	X	Port D2	-	Analog input 3 [AFR2] Timer 52 - channel 3 [AFR1]
20	PD3/ AIN4/ TIM5_CH2/ ADC_ETR	I/O	X	X	X	HS	O3	X	X	Port D3	Analog input 4 Timer 52 - channel 2/ADC external trigger	-

1. I/O pins used simultaneously for high current source/sink must be uniformly spaced around the package. In addition, the total driven current must respect the absolute maximum ratings (see [Section 9.2: Absolute maximum ratings](#)).
2. When the MCU is in Halt/Active-halt mode, PA1 is automatically configured in input weak pull-up and cannot be used for waking up the device. In this mode, the output state of PA1 is not driven. It is recommended to use PA1 only in input mode if Halt/Active-halt is used in the application.
3. In the open-drain output column, 'T' defines a true open-drain I/O (P-buffer, weak pull-up, and protection diode to VDD are not implemented)
4. The PD1 pin is in input pull-up during the reset phase and after internal reset release.

Table 7. STM8AF6223A TSSOP20 pin description

TSSOP	Pin name	Type	Input			Output				Main function (after reset)	Default alternate function	Alternate function after remap [option bit]
			floating	wpu	Ext. interrupt	High sink ⁽¹⁾	Speed	OD	PP			
1	PD4/ TIM5_CH1/ BEEP/SPI_NSS [LINUART_CK]	I/O	X	X	X	HS	O3	X	X	Port D4	Timer 5 - channel 1/BEEP output	LINUART clock [AFR2]
2	PD5/ AIN5/ LINUART_TX	I/O	X	X	X	HS	O3	X	X	Port D5	Analog input 5/ LINUART data transmit	-

Table 8. STM8AF6226 LQFP32/VFQPN32 pin description (continued)

LQFP32 VFQPN32	Pin name	Type	Input			Output				Main function (after reset)	Default alternate function	Alternate function after remap [option bit]
			floating	wpu	Ext. interrupt	High sink ⁽¹⁾	Speed	OD	PP			
17	PE5/ SPI_NSS [TIM1_CH1N]	I/O	X	X	X	HS	O3	X	X	Port E5	SPI master/ slave select	Timer 1 - inverted channel 1 [AFR1:0]
18	PC1/ TIM1_CH1/ LINUART_CK [TIM1_CH2N]	I/O	X	X	X	HS	O3	X	X	Port C1	Timer 1 - channel 1 LINUART clock	Timer 1 - inverted channel 2 [AFR1:0]
19	PC2/ TIM1_CH2 [TIM1_CH3N]	I/O	X	X	X	HS	O3	X	X	Port C2	Timer 1 - channel 2	Timer 1 - inverted channel 3 [AFR1:0]
20	PC3/ TIM1_CH3/[TLI] [TIM1_CH1N]	I/O	X	X	X	HS	O3	X	X	Port C3	Timer 1 - channel 3	Top level interrupt [AFR3] Timer 1 inverted channel 1 [AFR7]
21	PC4/ TIM1_CH4/ CLK_CCO/[AIN 2][TIM1_CH2N]	I/O	X	X	X	HS	O3	X	X	Port C4	Timer 1 - channel 4 /configurable clock output	Analog input 2 [AFR2]Timer 1 inverted channel 2 [AFR7]
22	PC5/SPI_SCK [TIM5_CH1]	I/O	X	X	X	HS	O3	X	X	Port C5	SPI clock	Timer 5 channel 1 [AFR0]
23	PC6/ SPI_MOSI [TIM1_CH1]	I/O	X	X	X	HS	O3	X	X	Port C6	PI master out/slave in	Timer 1 channel 1 [AFR0]
24	PC7/ SPI_MISO [TIM1_CH2]	I/O	X	X	X	HS	O3	X	X	Port C7	SPI master in/ slave out	Timer 1 channel 2[AFR0]
25	PD0/ TIM1_BKIN [CLK_CCO]	I/O	X	X	X	HS	O3	X	X	Port D0	Timer 1 - break input	Configurable clock output [AFR5]
26	PD1/ SWIM ⁽⁴⁾	I/O	X	X	X	HS	O4	X	X	Port D1	SWIM data interface	-

5.3 Alternate function remapping

As shown in the rightmost column of [Table 6](#), [Table 7](#) and [Table 8](#) some alternate functions can be remapped at different I/O ports by programming one of eight AFR (alternate function remap) option bits. Refer to [Section 8: Option bytes on page 46](#). When the remapping option is active, the default alternate function is no longer available.

To use an alternate function, the corresponding peripheral must be enabled in the peripheral registers.

Alternate function remapping does not effect GPIO capabilities of the I/O ports (see the GPIO section of STM8S series and STM8AF series 8-bit microcontrollers reference manual, RM0016).

Table 11. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 50B3	RST	RST_SR	Reset status register	0xXX ⁽¹⁾
0x00 50B4 to 0x00 50BF	Reserved area (12 byte)			
0x00 50C0	CLK	CLK_ICKR	Internal clock control register	0x01
0x00 50C1		CLK_ECKR	External clock control register	0x00
0x00 50C2	Reserved area (1 byte)			
0x00 50C3	CLK	CLK_CMSR	Clock master status register	0xE1
0x00 50C4		CLK_SWR	Clock master switch register	0xE1
0x00 50C5		CLK_SWCR	Clock switch control register	0xFF
0x00 50C6		CLK_CKDIVR	Clock divider register	0x18
0x00 50C7		CLK_PCKENR1	Peripheral clock gating register 1	0xFF
0x00 50C8		CLK_CSSR	Clock security system register	0x00
0x00 50C9		CLK_CCOR	Configurable clock control register	0x00
0x00 50CA		CLK_PCKENR2	Peripheral clock gating register 2	0xFF
0x00 50CB	Reserved area (1 byte)			
0x00 50CC	CLK	CLK_HSITRIMR	HSI clock calibration trimming register	0x00
0x00 50CD		CLK_SWIMCCR	SWIM clock control register	0bXXXX XXX0
0x00 50CE to 0x00 50D0	Reserved area (3 byte)			
0x00 50D1	WWDG	WWDG_CR	WWDG control register	0x7F
0x00 50D2		WWDG_WR	WWDG window register	0x7F
0x00 50D3 to 0x00 50DF	Reserved area (13 byte)			
0x00 50E0	IWDG	IWDG_KR	IWDG key register	0xFF ⁽²⁾
0x00 50E1		IWDG_PR	IWDG prescaler register	0x00
0x00 50E2		IWDG_RLR	IWDG reload register	0xFF
0x00 50E3 to 0x00 50EF	Reserved area (13 byte)			
0x00 50F0	AWU	AWU_CSR1	AWU control/status register 1	0x00
0x00 50F1		AWU_APR	AWU asynchronous prescaler buffer register	0x3F
0x00 50F2		AWU_TBR	AWU timebase selection register	0x00
0x00 50F3	BEEP	BEEP_CSR	BEEP control/status register	0x1F
0x00 50F4 to 0x00 50FF	Reserved area (12 byte)			

Table 11. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 5230	LINUART	UART4_SR	LINUART status register	0xC0
0x00 5231		UART4_DR	LINUART data register	0xFF
0x00 5232		UART4_BRR1	LINUART baud rate register 1	0x00
0x00 5233		UART4_BRR2	LINUART baud rate register 2	0x00
0x00 5234		UART4_CR1	LINUART control register 1	0x00
0x00 5235		UART4_CR2	LINUART control register 2	0x00
0x00 5236		UART4_CR3	LINUART control register 3	0x00
0x00 5237		UART4_CR4	LINUART control register 4	0x00
0x00 5238		Reserved		
0x00 5239		UART4_CR6	LINUART control register 6	0x00
0x00 523A		UART4_GTR	LINUART guard time register	0x00
0x00 523B		UART4_PSCR	LINUART prescaler	0x00
0x00 523C to 0x00 523F	Reserved area (20 byte)			

6.2.2 CPU/SWIM/debug module/interrupt controller registers

Table 12. CPU/SWIM/debug module/interrupt controller registers

Address	Block	Register label	Register name	Reset status
0x00 7F00	CPU ⁽¹⁾	A	Accumulator	0x00
0x00 7F01		PCE	Program counter extended	0x00
0x00 7F02		PCH	Program counter high	0x00
0x00 7F03		PCL	Program counter low	0x00
0x00 7F04		XH	X index register high	0x00
0x00 7F05		XL	X index register low	0x00
0x00 7F06		YH	Y index register high	0x00
0x00 7F07		YL	Y index register low	0x00
0x00 7F08		SPH	Stack pointer high	0x03
0x00 7F09		SPL	Stack pointer low	0xFF
0x00 7F0A		CCR	Condition code register	0x28
0x00 7F0B to 0x00 7F5F	Reserved area (85 byte)			
0x00 7F60	CPU	CFG_GCR	Global configuration register	0x00
0x00 7F70	ITC	ITC_SPR1	Interrupt software priority register 1	0xFF
0x00 7F71		ITC_SPR2	Interrupt software priority register 2	0xFF
0x00 7F72		ITC_SPR3	Interrupt software priority register 3	0xFF
0x00 7F73		ITC_SPR4	Interrupt software priority register 4	0xFF
0x00 7F74		ITC_SPR5	Interrupt software priority register 5	0xFF
0x00 7F75		ITC_SPR6	Interrupt software priority register 6	0xFF
0x00 7F76		ITC_SPR7	Interrupt software priority register 7	0xFF
0x00 7F77		ITC_SPR8	Interrupt software priority register 8	0xFF
0x00 7F78 to 0x00 7F79	Reserved area (2 byte)			
0x00 7F80	SWIM	SWIM_CSR	SWIM control status register	0x00
0x00 7F81 to 0x00 7F8F	Reserved area (15 byte)			

Table 13. Interrupt mapping (continued)

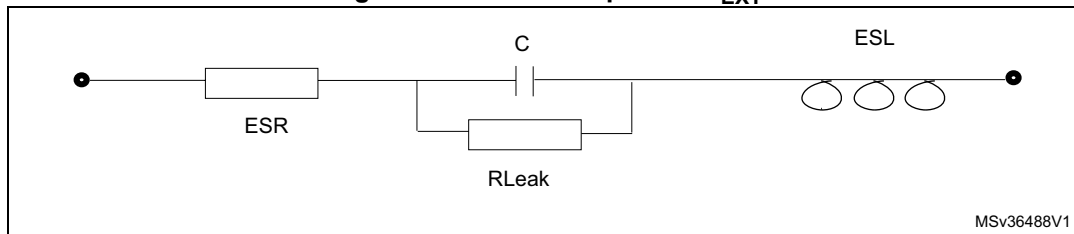
Priority	Source block	Description	Wakeup from halt mode	Wakeup from active-halt mode	Interrupt vector address
23	TIM6	TIM6 update/overflow/trigger	-	-	0x00 8064
24	Flash	EOP/WR_PG_DIS	-	-	0x00 8068

1. Except PA1.

9.3.1 VCAP external capacitor

Stabilization for the main regulator is achieved connecting an external capacitor C_{EXT} to the V_{CAP} pin. C_{EXT} is specified in [Table 26](#). Care should be taken to limit the series inductance to less than 15 nH.

Figure 10. External capacitor C_{EXT}



1. Legend: ESR is the equivalent series resistance and ESL is the equivalent inductance.

9.3.2 Supply current characteristics

The current consumption is measured as described in [Section 4.3: Interrupt controller](#).

Total current consumption in run mode

The MCU is placed under the following conditions:

- All I/O pins in input mode with a static value at V_{DD} or V_{SS} (no load)
- All peripherals are disabled (clock stopped by peripheral clock gating registers) except if explicitly mentioned.

Subject to general operating conditions for V_{DD} and T_A .

Unless otherwise specified, data are based on characterization results, and not tested in production.

Table 28. Total current consumption with code execution in run mode at $V_{DD} = 5\text{ V}$

Symbol	Parameter	Conditions		Typ	Max	Unit
$I_{DD(RUN)}$	Supply current in run mode, code executed from RAM	$f_{CPU} = f_{MASTER} = 16\text{ MHz}$	HSE crystal osc. (16 MHz)	2.3	-	mA
			HSE user ext. clock (16 MHz)	2	2.35	
			HSI RC osc. (16 MHz)	1.7	2 ⁽¹⁾	
		$f_{CPU} = f_{MASTER}/128 = 125\text{ kHz}$	HSE user ext. clock (16 MHz)	0.86	-	
			HSI RC osc. (16 MHz)	0.7	0.87	
		$f_{CPU} = f_{MASTER}/128 = 15.625\text{ kHz}$	HSI RC osc. (16 MHz/8)	0.46	0.58	
		$f_{CPU} = f_{MASTER} = 28\text{ kHz}$	LSI RC osc. (128 kHz)	0.41	0.55	

Total current consumption in wait mode

Unless otherwise specified, data based are on characterization results, and not tested in production.

Table 30. Total current consumption in wait mode at $V_{DD} = 5\text{ V}$

Symbol	Parameter	Conditions		Typ	Max	Unit
$I_{DD(WFI)}$	Supply current in wait mode	$f_{CPU} = f_{MASTER} = 16\text{ MHz}$	HSE crystal osc. (16 MHz)	1.6	-	mA
			HSE user ext. clock (16 MHz)	1.1	1.3	
			HSI RC osc. (16 MHz)	0.89	1.5 ⁽¹⁾	
		$f_{CPU} = f_{MASTER}/128 = 125\text{ kHz}$	HSI RC osc. (16 MHz)	0.7	0.88	
		$f_{CPU} = f_{MASTER}/128 = 15.625\text{ kHz}$	HSI RC osc. (16 MHz/8) ⁽²⁾	0.45	0.57	
		$f_{CPU} = f_{MASTER} = 128\text{ kHz}$	LSI RC osc. (128 kHz)	0.4	0.54	

1. Tested in production.

2. Default clock configuration measured with all peripherals off.

Table 31. Total current consumption in wait mode at $V_{DD} = 3.3\text{ V}$

Symbol	Parameter	Conditions		Typ	Max ⁽¹⁾	Unit
$I_{DD(WFI)}$	Supply current in wait mode	$f_{CPU} = f_{MASTER} = 16\text{ MHz}$	HSE crystal osc. (16 MHz)	1.1	-	mA
			HSE user ext. clock (16 MHz)	1.1	1.3	
			HSI RC osc. (16 MHz)	0.89	1.1	
		$f_{CPU} = f_{MASTER}/128 = 125\text{ kHz}$	HSI RC osc. (16 MHz)	0.7	0.88	
		$f_{CPU} = f_{MASTER}/128 = 15.625\text{ kHz}$	HSI RC osc. (16 MHz/8) ⁽²⁾	0.45	0.57	
		$f_{CPU} = f_{MASTER} = 128\text{ kHz}$	LSI RC osc. (128 kHz)	0.4	0.54	

1. Guaranteed by characterization results.

2. Default clock configuration measured with all peripherals off.

Current consumption curves

The following figures show typical current consumption measured with code executing in RAM.

Figure 11. Typ $I_{DD(RUN)}$ vs. V_{DD} HSE user external clock, $f_{CPU} = 16$ MHz

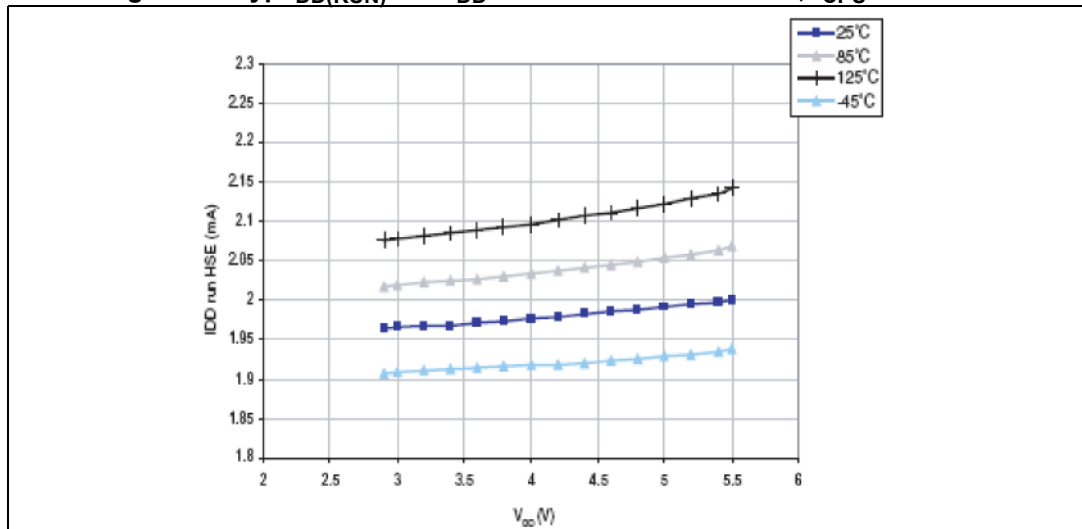


Figure 12. Typ $I_{DD(RUN)}$ vs. f_{CPU} HSE user external clock, $V_{DD} = 5$ V

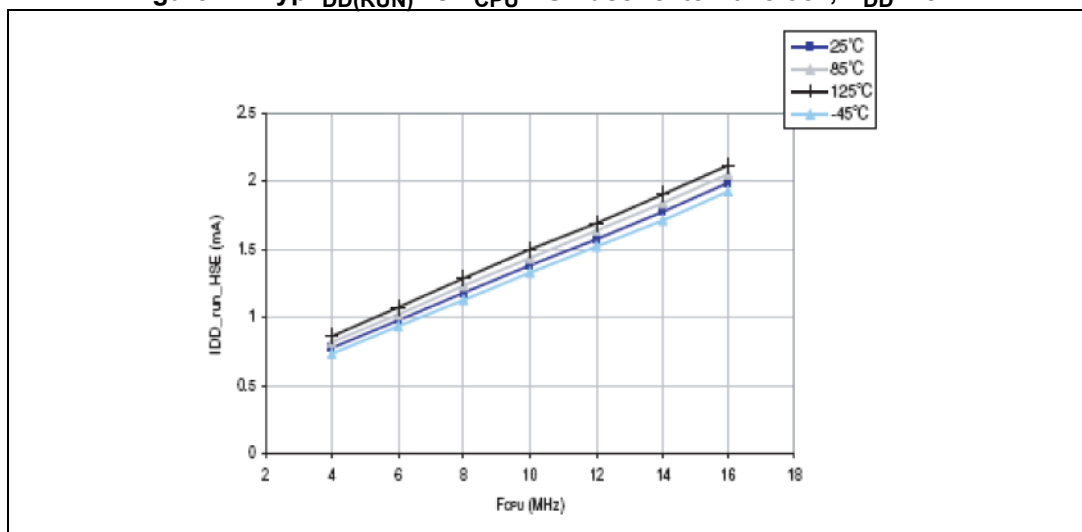


Figure 13. Typ $I_{DD(RUN)}$ vs. V_{DD} HSEI RC osc., $f_{CPU} = 16$ MHz

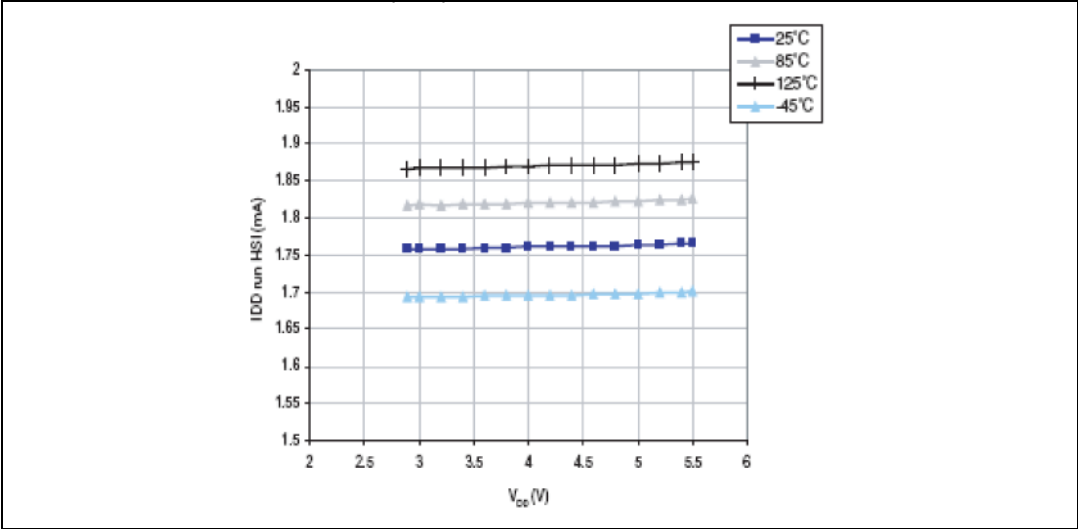
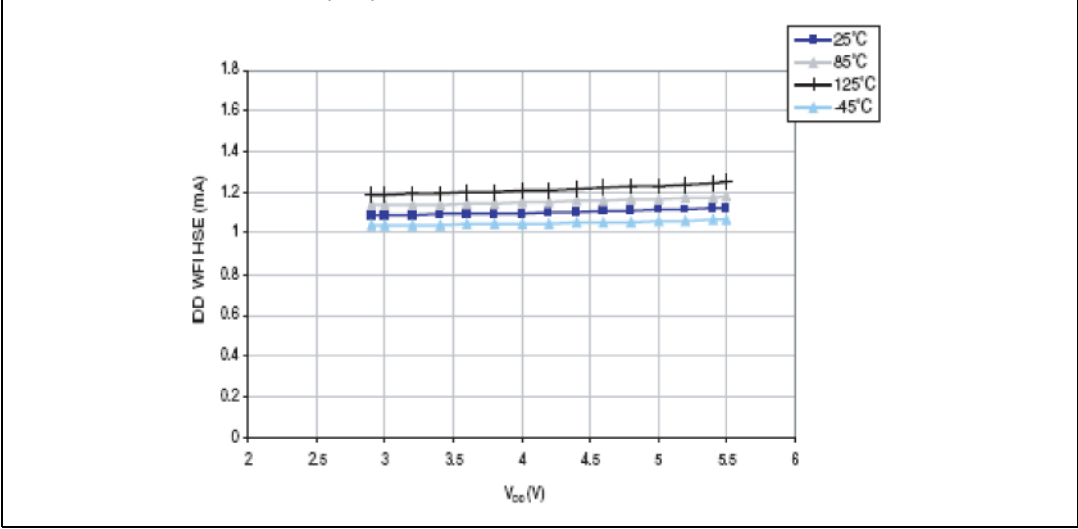


Figure 14. Typ $I_{DD(WFI)}$ vs. V_{DD} HSE user external clock, $f_{CPU} = 16$ MHz



HSE crystal/ceramic resonator oscillator

The HSE clock can be supplied with a 1 to 16 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph is based on characterization results with specified typical external components. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details (frequency, package, accuracy...).

Table 40. HSE oscillator characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{HSE}	External high-speed oscillator frequency	-	1	-	16	MHz
R_F	Feedback resistor	-	-	220	-	k Ω
$C^{(1)}$	Recommended load capacitance ⁽²⁾	-	-	-	20	pF
$I_{DD(HSE)}$	HSE oscillator power consumption	$C = 20$ pF, $f_{OSC} = 16$ MHz	-	-	6 (startup) 1.6 (stabilized) ⁽³⁾	mA
		$C = 10$ pF, $f_{OSC} = 16$ MHz	-	-	6 (startup) 1.2 (stabilized) ⁽³⁾	
g_m	Oscillator transconductance	-	5	-	-	mA/V
$t_{SU(HSE)}^{(4)}$	Startup time	V_{DD} is stabilized	-	1	-	ms

1. C is approximately equivalent to 2 x crystal C_{LOAD} .
2. The oscillator selection can be optimized in terms of supply current using a high quality resonator with small R_m value. Refer to the crystal manufacturer for more details.
3. Guaranteed by characterization results.
4. $t_{SU(HSE)}$ is the startup time measured from the moment it is enabled (by software) until a stabilized 16 MHz oscillation is reached. The value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

Figure 18. HSE oscillator circuit diagram

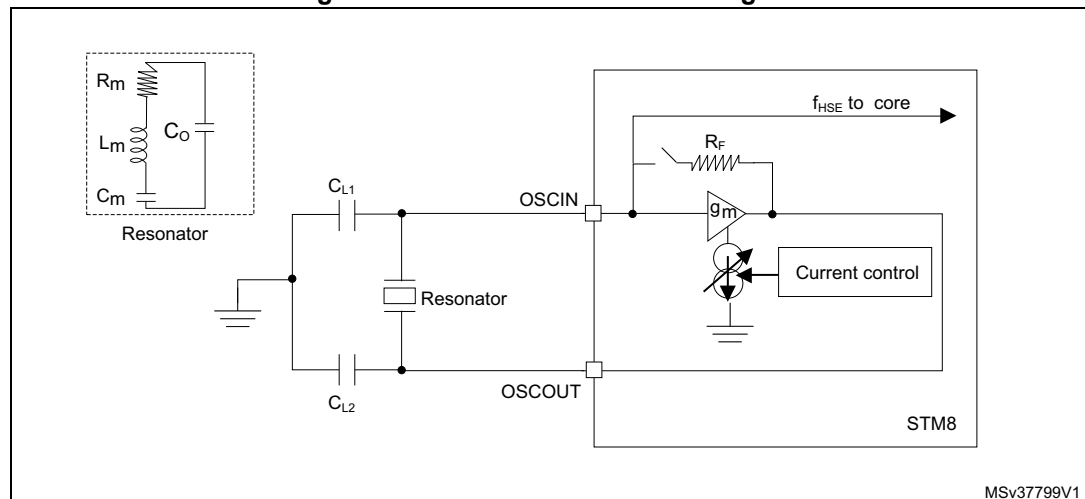
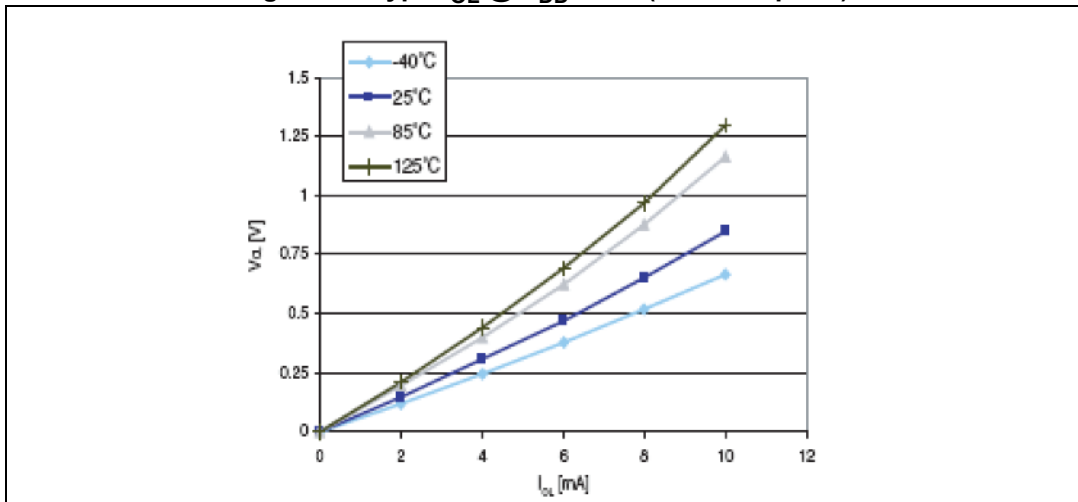
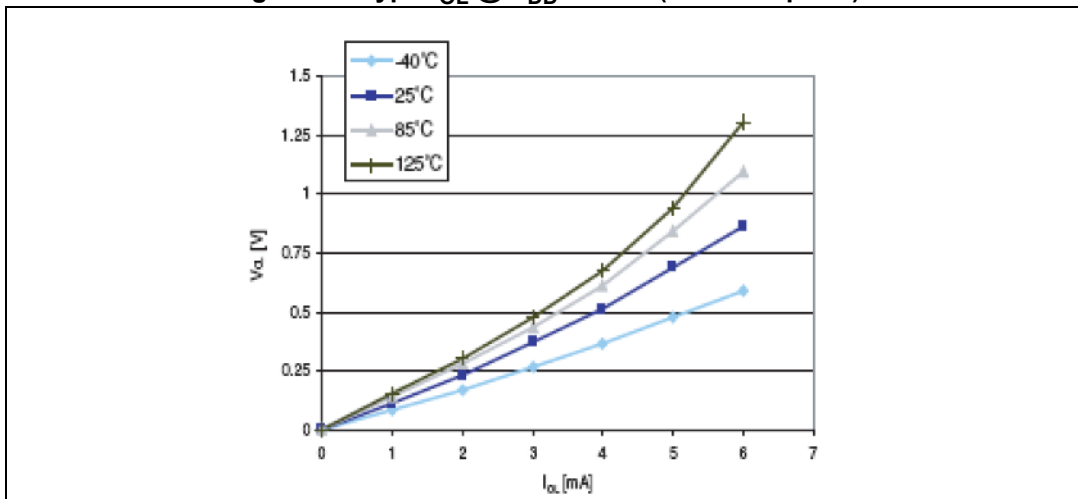


Table 50. Output driving current (high sink ports)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{OL}	Output low level with 8 pins sunk	$I_{IO} = 10 \text{ mA}$, $V_{DD} = 5 \text{ V}$	-	0.8	V
	Output low level with 4 pins sunk	$I_{IO} = 10 \text{ mA}$, $V_{DD} = 3.3 \text{ V}$	-	1.0 ⁽¹⁾	
		$I_{IO} = 20 \text{ mA}$, $V_{DD} = 5 \text{ V}$		1.5 ⁽¹⁾	
V_{OH}	Output high level with 8 pins sourced	$I_{IO} = 10 \text{ mA}$, $V_{DD} = 5 \text{ V}$	4.0	-	
	Output high level with 4 pins sourced	$I_{IO} = 10 \text{ mA}$, $V_{DD} = 3.3 \text{ V}$	2.1 ⁽¹⁾	-	
		$I_{IO} = 20 \text{ mA}$, $V_{DD} = 5 \text{ V}$	3.3 ⁽¹⁾	-	

1. Guaranteed by characterization results.

Figure 22. Typ. V_{OL} @ $V_{DD} = 5 \text{ V}$ (standard ports)Figure 23. Typ. V_{OL} @ $V_{DD} = 3.3 \text{ V}$ (standard ports)

9.3.10 10-bit ADC characteristics

Subject to general operating conditions for V_{DD} , f_{MASTER} , and T_A unless otherwise specified.

Table 54. ADC characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f _{ADC}	ADC clock frequency	V _{DD} = 3 to 5.5 V	1	-	4	MHz
		V _{DD} = 4.5 to 5.5 V	1	-	6	
V _{AIN}	Conversion voltage range ⁽¹⁾	-	V _{SS}	-	V _{DD}	V
V _{BGREF}	Internal bandgap reference voltage	V _{DD} = 3 to 5.5 V	1.19 ⁽²⁾	1.22	1.25 ⁽²⁾	V
C _{ADC}	Internal sample and hold capacitor	-	-	3	-	pF
t _S ⁽¹⁾	Minimum sampling time	f _{ADC} = 4MHz	-	0.75	-	μs
		f _{ADC} = 6 MHz	-	0.5	-	
t _{STAB}	Wakeup time from standby	-	-	7	-	
t _{CONV}	Minimum total conversion time including sampling time, 10-bit resolution	f _{ADC} = 4 Hz	3.5			μs
		f _{ADC} = 6 MHz	2.33			
		-	14			1/f _{ADC}

1. During the sample time the input capacitance C_{AIN} (3 pF max) can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within t_S . After the end of the sample time t_S , changes of the analog input voltage have no effect on the conversion result. Values for the sample clock t_S depend on programming.

2. Tested in production.

Electromagnetic interference (EMI)

Based on a simple application running on the product (toggling 2 LEDs through the I/O ports), the product is monitored in terms of emission. This emission test is in line with the norm IEC 61967-2 which specifies the board and the loading of each pin.

Table 58. EMI data

Symbol	Parameter	Conditions				Unit
		General conditions	Monitored frequency band	Max f _{HSE} /f _{CPU} ⁽¹⁾		
				16 MHz/ 8 MHz	16 MHz/ 16 MHz	
S _{EMI}	Peak level	V _{DD} = 5 V, T _A = 25 °C, LQFP32 package conforming to IEC 61967-2	0.1 MHz to 30 MHz	5	5	dBμV
			30 MHz to 130 MHz	4	5	
			130 MHz to 1 GHz	5	5	
	EMI level		—	2.5	2.5	level

1. Guaranteed by characterization results.

Absolute maximum ratings (electrical sensitivity)

Based on three different tests (ESD, DLU and LU) using specific measurement methods, the product is stressed to determine its performance in terms of electrical sensitivity. For more details, refer to the application note AN1181.

Electrostatic discharge (ESD)

Electrostatic discharges (one positive then one negative pulses separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts*(n+1) supply pin). One model can be simulated: Human body model. This test conforms to the JESD22-A114A/A115A standard. For more details, refer to the application note AN1181.

Table 59. ESD absolute maximum ratings

Symbol	Ratings	Conditions	Class	Maximum value ⁽¹⁾	Unit
$V_{ESD(HBM)}$	Electrostatic discharge voltage (Human body model)	$T_A = 25\text{ }^\circ\text{C}$, conforming to JESD22-A114	3A	4000	V
$V_{ESD(CDM)}$	Electrostatic discharge voltage (Charge device model)	$T_A = 25\text{ }^\circ\text{C}$, conforming to JESD22-C101	3	500	
$V_{ESD(MM)}$	Electrostatic discharge voltage (Machine model)	$T_A = 25\text{ }^\circ\text{C}$, conforming to JESD22-A115	B	200	

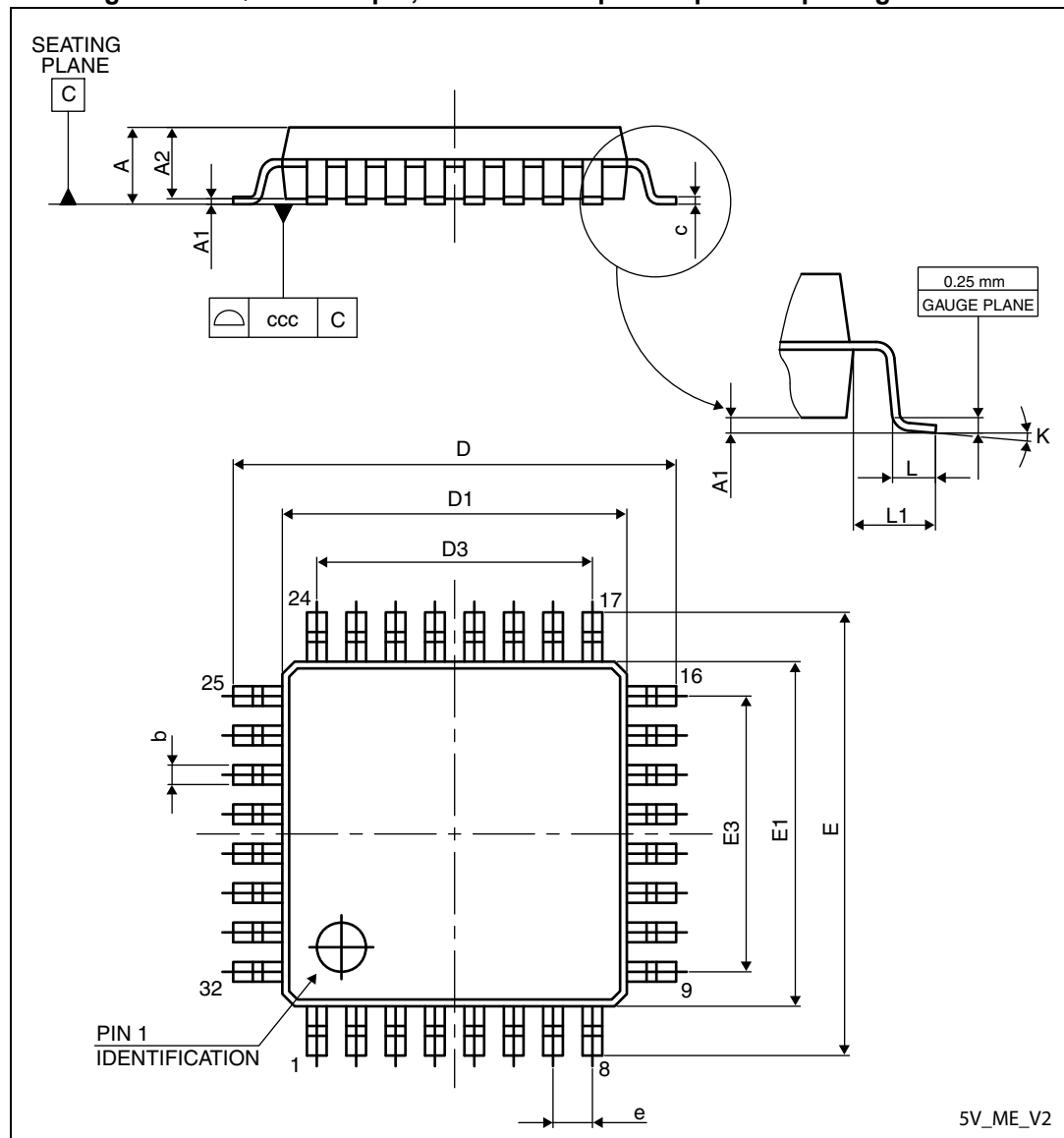
1. Guaranteed by characterization results.

10 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

10.1 LQFP32 package information

Figure 42. LQFP32 - 32-pin, 7 x 7 mm low-profile quad flat package outline



1. Drawing is not to scale.

Assuming the following application conditions:

Maximum ambient temperature $T_{Amax} = 75\text{ }^{\circ}\text{C}$ (measured according to JESD51-2),

$I_{DDmax} = 8\text{ mA}$, $V_{DD} = 5\text{ V}$

Maximum 20 I/Os used at the same time in output at low level with:

$I_{OL} = 8\text{ mA}$, $V_{OL} = 0.4\text{ V}$

$P_{INTmax} = 8\text{ mA} \times 5\text{ V} = 400\text{ mW}$

$P_{IOmax} = 20 \times 8\text{ mA} \times 0.4\text{ V} = 64\text{ mW}$

This gives: $P_{INTmax} = 400\text{ mW}$ and $P_{IOmax} = 64\text{ mW}$:

$P_{Dmax} = 400\text{ mW} + 64\text{ mW}$

Thus: $P_{Dmax} = 464\text{ mW}$.

Using the values obtained in [Table 64: Thermal characteristics on page 101](#) T_{Jmax} is calculated as follows:

For LQFP32 $60\text{ }^{\circ}\text{C/W}$

$T_{Jmax} = 75\text{ }^{\circ}\text{C} + (60\text{ }^{\circ}\text{C/W} \times 464\text{ mW}) = 75\text{ }^{\circ}\text{C} + 27.8\text{ }^{\circ}\text{C} = 102.8\text{ }^{\circ}\text{C}$

This is within the range of the suffix C version parts ($-40 < T_J < 125\text{ }^{\circ}\text{C}$).

Parts must be ordered at least with the temperature range suffix C.